Substitute for form 1449A/PTO	Complete if known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT *(use as many sheets as necessary)*	Application Number	10/065,220
	Filing Date	September 26, 2002
	First Named Inventor	Raj Kumar JAIN
	Art Unit	2818
	Examiner Name	Thong Quoc LE
Sheet	1	of	1	Attorney Docket Number	00P19153US

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²
TL		DAISABURO TAKASHIMA, IWAO KUNISHIMA; "High-Density Chain Ferroelectric Random Access Memory (Chain FRAM)"; IEEE Journal of Solid-State Circuits, Vol. 33, No. 5; May 1998; Pgs 787-792	

Examiner Signature	*Uhoyle*	Date Considered	2/21/03

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¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached.
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